## NSN 5961-01-298-0236

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View Online at https://aerobasegroup.com/nsn/5961-01-298-0236

## **Inclosure Material:**

Metal

**Overall Length:** 

1.550 inches

## **Overall Height:**

0.330 inches

### **Overall Width:**

1.550 inches

## **Mounting Facility Quantity:**

2

### Internal Configuration:

Junction contact-darlington connected

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

## Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

### **Features Provided:**

Hermetically sealed case

## Criticality Code Justification:

Feat

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

120.0 collector to base voltage/static/emitter open and 120.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

100.00 amperes source cutoff current and 2.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

300.0 watts small-signal input power, common-collector absolute

#### Transfer Ratio:

400.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

#### **Special Features:**

Weapon system essential; junction pattern arrangement; pnp

#### **Test Data Document:**

97942-587r904 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Terminal Type And Quantity:**

2 pin and 1 case

#### Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A110a0

